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Gapless chiral excitons in thin films of topological insulators

S. A. Jafari[1, 2, 3]

[1]*Department of Physics, Sharif University of Technology, Tehran 11155-9161, Iran*
[2]*Center of excellence for Complex Systems and Condensed Matter (CSCM), Sharif University of Technology, Tehran 1458889694, Iran*
[3]*School of Physics, Institute for Research in Fundamental Sciences, Tehran 19395-5531, Iran*

In a nanoscopic thin film of a strong topological insulator (TI) the Coulomb interaction in the channel that exchanges the two electrons with the same chirality in two different planes of the slab takes advantage of the minus sign resulting from such "exchange" and gives rise to a bound state between the positive energy states in one surface and the negative energy states in the opposite surfaces. Therefore particle and hole pairs in the *undoped* Dirac cone of the TI thin film form an inter-surface spin-singlet state that lies below the continuum of free particle-hole pairs. This mode is similar to the excitons of semiconductors, albeit formed between the electron and hole pairs from two different two-dimensional surfaces. For low-momenta the dispersion relation characterizing this collective mode is linear. Experimental comparison of two slabs with different thicknesses can capture the exponential dependence of the present effect on the slab thickness.

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INTRODUCTION

Strong topological insulators (TI) are characterized by a bulk gap, while the surface surrounding the material hosts odd number of gapless Dirac fermions [1, 2]. The classification of the topological insulators are based on the non-interacting picture and their basic band structure [3]. The gapless helical surface states are characteristic of topological insulators as long as the many-body interactions can be ignored. Therefore an important question is, what happens when interactions are turned on? Nature of collective excitations of the helical metallic states [4] and possible instabilities [5] are of particular interest. If the interactions are of short range nature and are strong enough to destroy the metallic state of the surface, a Mott insulating state in the surface is expected, albeit with surface spinon bands [6]. When the interactions are not strong enough to destroy the metallic nature of the surface states, the Coulomb interactions within a surface of a TI doped away from Dirac point gives rise to plasmonic and zero sound collective excitations in the helical metallic state of the surface [4]. Such collective excitations require a Fermi surface and hence disappear in the undoped surface Dirac cone, $\mu = 0$.

The Dirac cone of undoped graphene supports a particle-hole *bound state* – i.e. an split-off state below the free particle-hole continuum (PHC) – which disperses linearly with momentum [7–9]. In contrast to the anti-bonding nature of plasmon excitations [10], a minus sign required to render the interaction vertex attractive is provided by the *exchange* interactions [7]. The Dirac cone describing the topological surface states features a spin-momentum locking [1] which makes the physical spin inaccessible for the exchange process. The question is then, can there be a mechanism to give rise to a bound state below the PHC of the free Dirac fermions topological insulators? The physical spin of the electrons in helical metals is locked to momentum and hence the spin-exchange scattering requires their momentum to be reversed. But such a back-scattering is prohibited by the chiral nature of carriers. Therefore unlike graphene [7], the combination of time-reversal symmetry and the chiral nature of helical states prevents taking advantage of the minus sign (attraction) in the exchange Coulomb vertex in the spin-triplet particle-hole channel. In this work we show that when the TI is cut into a thin film the two surfaces can be described by a pseudo-spin $\hat{\tau}$ taking on two values $\tau^z(\equiv \tau) = \pm 1$. Then *the τ-exchange scattering part of the Coulomb interaction will provide attractive interaction between the positive-energy state from one surface and a negative-energy state from the other surface* and hence leads to a bound state in the particle-hole channel which is if singlet nature with respect to spin, but can be considered of a triplet nature with respect to pseudo-spin $\hat{\tau}$. This is akin to excitons of a semiconductor, but with particle and hole states coming from two different surfaces $\tau = \pm$ surfaces of the TI slab. It can also be thought of as the "pseudo-spin" version of a collective mode in the Dirac cone of graphene [7, 8]. Since the constituent particle and hole pairs come from two different planes, the center of mass of this collective mode will be in a bisecting plane parallel to the surface. Therefore in nanoscopic thin films of TIs where inter-surface Coulomb interactions are substantial in addition to the opposite-chirality Fermionic modes corresponding to single-particle helical states on the $\tau = \pm$ surfaces of a TI, there will be an additional two dimensional branch of collective excitations with spin-singlet bosonic character.

For an slab of TI with thickness ℓ, the Coulomb energy scale is be given by $e^2/(\epsilon_d \ell)$ where ϵ_d is the relative dielectric constant of the insulating medium (the bulk states) separating the two surfaces. The separation ℓ serves to tune the strength of interactions for a fixed bandwidth of surface states. For nanoscopic separations on the scale of $\ell \sim 10$ nm, in one hand the strength of the Coulomb interaction will become comparable to the bandwidth of the surface states [11]. On the other hand such separation is large enough to prevent the direct hybridization of the atomic orbitals on the opposite surfaces, and

hence the single-particle part of the spectrum is protected from gap opening and will continue to be a gapless Dirac theory. Increasing the strength of τ-off-diagonal interactions is expected to give rise to fascinating possibilities, including the proposal of topological excitonic condensation by Seradjeh and coworkers [5].

NON-INTERACTING HAMILTONIAN

To fix the notations for the rest of the paper, let us summarize the non-interacting part of the Hamiltonian of a TI thin film and discuss the relevant matrix elements. The low-energy effective theory describing the gapless metallic states on the surface of a TI is the so called "helical metal" and is given by [1], $H_0 = v_F \sum_{\mathbf{k}} c^\dagger_{\mathbf{k}} \hat{n}.(\mathbf{k} \times \vec{\sigma}) c_{\mathbf{k}}$ where the two-dimensional momentum $\mathbf{k}$ (we set $\hbar = 1$) is in the surface characterized by normal vector $\hat{n}$. The momentum is locked to its spin $\vec{\sigma}$. We use the spinor notation $c^\dagger_{\mathbf{k}} = (c^\dagger_{\uparrow\mathbf{k}}, c^\dagger_{\downarrow\mathbf{k}})$ where $\uparrow$ and $\downarrow$ are the z-component of the spin of electrons. When two opposite surfaces labeled by the pseudospin values $\tau = \pm$ are brought to nano-meter distance ℓ, as long as the surfaces are not close enough to allow for the overlap of atomic wave-functions the Hamiltonian of the thin film will be given by two copies of the above Dirac model as,

$$H_0^{\rm slab} = v_F \sum_{\tau\mathbf{k}} c^\dagger_{\tau\mathbf{k}} \left[\tau \hat{z}.(\mathbf{k} \times \vec{\sigma})\right] c_{\tau\mathbf{k}}. \tag{1}$$

A constant energy configuration within this Hamiltonian is described by a circulating pattern of in-plane spin texture oriented perpendicular to their two dimensional momentum vector $\mathbf{k}$ [2]. If we denote the azimuthal angle of $\mathbf{k}$ with respect to the k_x axis with $\theta_{\mathbf{k}}$, then in terms of the $\pi/2$ rotated momentum vector $\tilde{k}$ whose azimuthal angle is $\varphi_{\mathbf{k}} = \theta_{\mathbf{k}} + \pi/2$, the 2×2 Hamiltonian matrix in the above equation will be given by,

$$h_{\tau\mathbf{k}} = \tau v_F k \begin{pmatrix} 0 & e^{-i\varphi_{\mathbf{k}}} \\ e^{i\varphi_{\mathbf{k}}} & 0 \end{pmatrix}, \tag{2}$$

where $k = |\mathbf{k}| = \sqrt{k_x^2 + k_y^2}$. The following transformation from $c_{\tau\sigma\mathbf{k}}$-basis to $a_{\tau\lambda\mathbf{k}}-$basis defined by

$$\begin{pmatrix} c_{\tau\uparrow\mathbf{k}} \\ c_{\tau\downarrow\mathbf{k}} \end{pmatrix} = \frac{\tau}{\sqrt{2}} \begin{pmatrix} 1 & 1 \\ e^{i\varphi_{\mathbf{k}}} & -e^{i\varphi_{\mathbf{k}}} \end{pmatrix} \begin{pmatrix} a_{\tau,+,\mathbf{k}} \\ a_{\tau,-,\mathbf{k}} \end{pmatrix}, \tag{3}$$

brings H_0 to diagonal format:

$$H_0^{\rm slab} = \sum_{\tau\lambda\mathbf{k}} \varepsilon_{\tau\lambda\mathbf{k}}\, a^\dagger_{\tau\lambda\mathbf{k}} a_{\tau\lambda\mathbf{k}}, \tag{4}$$

where the subscript $\lambda = \pm$ stands for the helicity and the cone like dispersion is given by $\varepsilon_{\tau\lambda\mathbf{k}} = \tau\lambda v_F k \equiv \tau\lambda\varepsilon_{\mathbf{k}}$. The eigen mode $|\tau\lambda\mathbf{k}\rangle$ of the helical metal is created by

$$a^\dagger_{\tau\lambda\mathbf{k}}|\text{vac}\rangle = \frac{\tau}{\sqrt{2}} \left(c^\dagger_{\tau\uparrow\mathbf{k}} + \lambda e^{i\varphi_{\mathbf{k}}} c^\dagger_{\tau\downarrow\mathbf{k}}\right)|\text{vac}\rangle. \tag{5}$$

The above eigen-states correspond neither to $|\uparrow\rangle$ nor $|\downarrow\rangle$ spin states. Therefore, while the energy eigen-modes correspond to spin-half ($S^2|\tau\lambda\mathbf{k}\rangle = 3\hbar^2/4|\tau\lambda\mathbf{k}\rangle$), their spin has no component perpendicular to the surface, i.e. $\langle\mathbf{k}\lambda|S_z|\mathbf{k}\lambda\rangle = 0$. Rather at each $\mathbf{k}$ point the eigen-state has a definite spin angular momentum in the transverse direction $\tilde{k}$ which is in the plane of the surface and perpendicular to $\mathbf{k}$. Such a locking between the spin angular momentum on the linear momentum roots in the coupling between spin and orbital motion and forces the planar spin of the positive and negative energy states in the same plane to be always in a opposite directions [2, 11]. Therefore low-momentum transfer excitations between negative and positive energy states will always correspond to spin-singlet particle-hole pairs. So it is not possible to take advantage of the spin-flip (exchange) processes in order to stabilize a bound state in the particle-hole channel as long as a fixed surface is concerned.

However, when the other surface of the TI is brought closer, the surfaces on the two sides of the slab can be labeled by $\tau = \pm$. The index τ for an infinitely large plane will be an attribute of the electron motion (constant of motion) and therefore a *pseudo-spin* τ emerges very naturally. The Coulomb interaction in the channel that "exchanges" the τ attributes (Fig. 1) can take advantage of this pseudo-spin structure. Hence the Coulomb repulsion between electrons translates into attraction between a positive energy state in one plane (say $\tau = +$) and the negative energy state in the opposite plane ($\tau = -$) and hence is expected to bind them below the PHC.

COLLECTIVE EXCITATIONS IN SLAB OF TOPOLOGICAL INSULATOR

In the plasmon and zero sound excitations considered in [4] for a single value of τ, only states with a fixed value of λ are involved, as they are intra-band excitations. But when the chemical potential is at the Dirac node, $\mu = 0$, both positive and negative energy states are expected to play role in the formation of the particle-hole bound state. The non-interacting part of the Hamiltonian $H_0^{\rm slab}$ describes electrons at $|\tau\lambda\mathbf{k}\rangle$ states, where the sign of energy is given by the product $\tau\lambda$ of the pseudo-spin value and the helicity. Hence a positive energy state from one plane and the negative energy state from

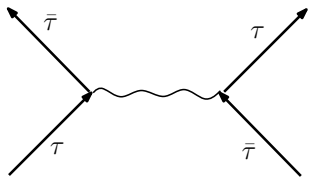

FIG. 1. Basic τ-exchange interaction responsible for the formation of inter-surface singlet exciton mode. The minus sign required to make the attraction interaction is generated by the exchange of τ attribute of the incoming states.

the opposite plane must have the same helicity λ. For an electron of given energy traveling in some direction in the surface τ whose planar spin is σ, there will be another state at the same energy corresponding to propagating electron in the opposite direction in plane $\bar{\tau}$ with the same planar spin σ. This can be alternatively thought of as a hole in the $\bar{\tau}$ surface whose spin is $\bar{\sigma}$ and propagates in the same direction as the electron in state corresponding to $|\tau,\sigma\rangle$. The resulting attraction between the $|\tau,\sigma\rangle$ electron and $|\bar{\tau},\bar{\sigma}\rangle$ hole propagating in the same direction binds them in the spin-singlet channel.

Now let us put the above idea in a formal setting. To do this, we employ an interaction term of the following form:

$$H^{\rm int}=\frac{1}{2\mathcal{A}}\sum_{\mathbf{q}\tau}\rho_{\mathbf{q}\tau}\rho_{-\mathbf{q}\bar{\tau}}v(\mathbf{q}), \tag{6}$$

which is the standard density-density Coulomb interaction and the density fluctuation $\rho_{\mathbf{q}\tau}$ is the Fourier component of the density operator at surface τ and $\mathcal{A}$ is the area of the thin film under consideration. A peculiar feature of the following problem would be due to the interaction $v(\mathbf{q})$: The momentum $\mathbf{q}\equiv(q_x,q_y)$ is a two dimensional momentum and the Coulomb interaction is between two planes separated by ℓ along the z-direction. Hence $v(\mathbf{q})$ is a partial Fourier transform or the three dimensional Coulomb potential with respect to planar momentum $\mathbf{q}$, which will be given by,

$$v(\mathbf{q})=\frac{e^2}{4\pi\epsilon_d}\frac{\exp(-q\ell)}{q}, \tag{7}$$

where the two surfaces are assumed to be at $z=0$ and $z=\ell$. In the basis where the $H_0^{\rm slab}$ is diagonal, the density operator at surface τ is represented as,

$$\rho_{\mathbf{q}\tau}=\sum_{\lambda\lambda'\mathbf{k}}a^\dagger_{\tau\lambda'\mathbf{k}'}\langle\tau\lambda'\mathbf{k}'|\tau\lambda\mathbf{k}\rangle\; a_{\tau\lambda\mathbf{k}}, \tag{8}$$

where $\mathbf{k}'=\mathbf{k}+\mathbf{q}$ is understood, and the wave-function overlap factors are,

$$F_{\tau'\lambda'\mathbf{k}',\tau\lambda\mathbf{k}}\equiv\langle\tau'\lambda'\mathbf{k}'|\tau\lambda\mathbf{k}\rangle=\tau\tau'\frac{1+\lambda\lambda' e^{i\varphi_{\mathbf{k}}-i\varphi_{\mathbf{k}'}}}{2}. \tag{9}$$

In the $\tau=\tau'$ case the above overlap factor reduces to the familiar factors in the two dimensional Dirac fermions of graphene [10]. In terms of the above density, the generic form of the interaction between the two surfaces of the slab will be $va^\dagger_\tau a^\dagger_{\bar{\tau}}a_{\bar{\tau}}a_\tau$. This interaction in the τ-flip channel depicted in Fig. 1 will become, $-va^\dagger_\tau a^\dagger_{\bar{\tau}}a_\tau a_{\bar{\tau}}$. This means that the incoming particles exchange their τ attribute, i.e. a particle from one surface τ is scatters to the other surface $\bar{\tau}$, and at the same time another particle scatters from surface $\bar{\tau}$ to surface τ. This minus sign formally manifests in the following calculations as the $\tau\tau'=-1$ factor multiplying the above wave-function overlap in the exchange channel. The following analysis shows that this process is responsible for formation of a exciton-like bound state between the positive energy states of one surface and negative energy state of the opposite surface. Let us consider a particle-hole excitation between the negative-energy states of one surface and the positive energy states of the other surface which will have the following form:

$$O_{\mathbf{K},\mathbf{Q}}=a^\dagger_{++\mathbf{K}'}a_{-+\mathbf{K}}, \tag{10}$$

where $\mathbf{K}'=\mathbf{K}+\mathbf{Q}$ and hence the total momentum of the particle-hole pair is $\mathbf{Q}$. Equation of motion for this operator is $i\partial_t O_{\mathbf{K},\mathbf{Q}}=[O_{\mathbf{K},\mathbf{Q}},H_0+H^{\rm int}]$. The commutator of $O_{\mathbf{K},\mathbf{Q}}$ with H_0 is,

$$[O_{\mathbf{K},\mathbf{Q}},H_0]=-\left(\varepsilon_{\mathbf{K}}+\varepsilon_{\mathbf{K}+\mathbf{Q}}\right)O_{\mathbf{K},\mathbf{Q}}, \tag{11}$$

which upon identification of $i\partial_t\equiv-\omega\times$ means that as far as the the non-interacting part of the Hamiltonian for the slab is considered the operator $O_{\mathbf{K},\mathbf{Q}}$ creates a free particle-hole pair with energy $\varepsilon_{\mathbf{K}}+\varepsilon_{\mathbf{K}+\mathbf{Q}}$. The commutation relation with $H^{\rm int}$ after a Hartree decomposition to close the equation of motion gives [8, 12],

$$\left[O_{\mathbf{K},\mathbf{Q}},H^{\rm int}\right]\approx-\frac{v(\mathbf{Q})}{\mathcal{A}}\left[n_{++\mathbf{K}'}-n_{-+\mathbf{K}}\right]\times \sum_{\mathbf{p}\mathbf{p}'}F_{++\mathbf{p}',-+\mathbf{p}}\;a^\dagger_{++\mathbf{p}'}a_{-+\mathbf{p}}\;\delta_{\mathbf{p}',\mathbf{p}+\mathbf{Q}} \tag{12}$$

Note that to obtain the above equation, the interactions in the channel that exchanges the $\eta=\tau\lambda$ index of the incoming particles is essential. The equations of motions (11) and (12) suggest that the collective operator defined in the last line of Eq. (12) satisfies the following collective mode equation:

$$\frac{1}{v(\mathbf{Q})}=\frac{1}{\mathcal{A}}\sum_{\mathbf{K}}\frac{n_{++\mathbf{K}'}-n_{-+\mathbf{K}}}{\omega-(\varepsilon_{\mathbf{K}}+\varepsilon_{\mathbf{K}'})}\times\frac{1+e^{i\theta_{\mathbf{K}\mathbf{K}'}}}{2}\equiv\chi_0, \tag{13}$$

where $\mathbf{K}'=\mathbf{K}+\mathbf{Q}$ is understood. Moreover $\theta_{\mathbf{K}\mathbf{K}'}=\varphi_{\mathbf{K}}-\varphi_{\mathbf{K}'}$, and $n_{\tau\lambda\mathbf{K}}$ is the expectation value $\langle a^\dagger_{\tau\lambda\mathbf{K}}a_{\tau\lambda\mathbf{K}}\rangle$. Due to the symmetry under $\mathbf{Q}\to-\mathbf{Q}$ in the above equation, the $\sin(\theta_{\mathbf{K}\mathbf{K}'})$ does not contribute to. The remaining integral is identical to those appearing in the polarization of undoped graphene which has been calculated by many authors [13], and gives rise to following simple form:

$$\chi_0=\frac{Q^2}{16\sqrt{Q^2v_F^2-\omega^2}}. \tag{14}$$

This bubble is real and positive inside the gap below the particle-hole continuum $\omega<Qv_F$. Hence the equation for the dispersion relation of the inter-surface spin-singlet exciton will become,

$$\omega=Qv_F\left(1-\tilde{\alpha}^2e^{-2Q\ell}\right)^{1/2}, \tag{15}$$

where $\tilde{\alpha}=\frac{1}{64\pi}\frac{e^2}{v_F}$ plays a role similar to fine structure constant. Indeed it can be written as $\tilde{\alpha}=\frac{c}{v_F}\frac{\alpha}{64\pi}$ where $\alpha\approx1/137$ is the fine structure constant. For Fermi velocities in the scale of 10^4-10^5m/s in the Bismuth family [14] one expects the range of values $\tilde{\alpha}\sim10^{-2}-10^{-1}$. According to this expression, an instability in the $\mathbf{Q}\to0$ limit can

be triggered when $\tilde{\alpha}$ can become large which is only possible by finding materials with smaller v_F. For the Bismuth family TIs, given the very small value of $\tilde{\alpha}$, such instability does not seem feasible. Smallness of $\tilde{\alpha}$ allows us to Taylor expand the RHS of the dispersion relation to get,

$$\omega \approx Qv_F \left(1 - \frac{1}{2}\tilde{\alpha}^2 e^{-2Q\ell}\right), \tag{16}$$

which defines the binding energy of the bosonic mode with respect to the lower edge of free particle-hole continuum as,

$$E_B = Qv_F \frac{\tilde{\alpha}^2}{2} e^{-2Q\ell}. \tag{17}$$

If the thickness ℓ of the slab becomes very large, the exponential factor will diminish the binding energy and the bosonic mode will be absorbed to the lower edge of the continuum of free particle-hole pairs. However when the ℓ is not very large, the dispersion relation (16) defines a relativistic branch of bosons. The boson velocity acquires the following form

$$\frac{v_B}{v_F} = 1 + \left(Q\ell - \frac{1}{2}\right) \ell\tilde{\alpha}^2 e^{-2Q\ell} \tag{18}$$

The maximum of the binding energy is obtained for $2Q\ell = 1$ and is $E_B^{\max} = \tilde{\alpha}^2 v_F/(4\ell)$. Below this point $v_B < v_F$ and above it $v_B > v_F$. At this point itself, v_B becomes equal to v_F. Therefore for practical purposes in the low momentum region define by $2Q\ell \lesssim 1$, one may assume that the bosonic branch is almost degenerate with Fermionic branch and has the approximate dispersion relation

$$\omega = Qv_B, \qquad v_B \lesssim v_F. \tag{19}$$

For $\ell = 1$nm, we expect $E_B^{\max} \sim 10^{-2}$ meV. Although the direct observation of the above excitonic mode is difficult, but it may have indirect consequences on the spectral properties of the Fermions themselves.

SUMMARY AND CONCLUSIONS

Using random phase approximation implemented by the equations of motion we explicitly constructed spin-singlet $\hat{\tau}$-triplet collective operators for a nano-meter thick film of topological insulator. The τ-exchange part of the Coulomb interaction gave rise to an attraction between the positive energy states of one surface and the negative energy states of the other surface. Such attraction results in a binding bosonic mode below the continuum of free particle-hole excitations. The binding energy has a characteristic $\exp(-Q\ell)$ dependence which vanishes when the thickness ℓ of the slab becomes very large and hence reduced to proper limit. Although the binding energy of the present inter-surface excitonic mode is a fraction of meV, but given its chiral nature, it is expected to leave Kerr and Faraday signatures in optical absorption [15]. The self-energy corrections from such inter-surface excitons will indirectly show up in angular resolved photo-emission spectroscopy and scanning tunneling spectroscopy. Such effects can become more pronounced by approaching the excitonic instability [16].

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